


AMENDMENTS TO THE SPECIFICATION

Please amend paragraph [0026] to reintroduce subscript notations that were lost during electronic (EFS) filing as follows:

 [0026] The group III-nitride compound 20 of the preferred embodiment includes binary compound materials of, for example, GaN, InN, AlN, ternary compound materials of, for example, $\text{In}_x\text{Ga}_{1-x}\text{N}$, $\text{Al}_y\text{Ga}_{1-y}\text{N}$, $\text{In}_z\text{Al}_{1-z}\text{N}$ and/or quaternary compound materials of, for example, $\text{In}_u\text{Al}_v\text{Ga}_{1-u-v}\text{N}$, where u , v , x , y , and z are fractional numbers between zero (0) and (1) exclusive and $u+v$ is a fractional number between zero (0) and (1) exclusive. Such group III-nitride compounds 20 are preferred as providing blue or ultraviolet emission (i.e., wavelengths below about 500 nm), having good reliability, and benefiting from a relatively mature processing technology. In the preferred embodiment, the group III-nitride compound 20 includes GaN. However, other materials are contemplated.
